PRODUCTS & Solutions





PRESENTATION

Exxelia is a leading designer and manufacturer of **high-reliability passive components** and **electromechanical solutions**. Exxelia was born in 2009 from the merge of several long-established companies with complementary activities and know-hows.

This powerful alliance of expertise enables the Group to provide a **unique and complete product portfolio** commonly used for power electronics, power generation, energy storage, and signal filtering functions in **harsh environments**.



EXPANDING PRODUCT PORTFOLIO







Ceramic & Tantalum Capacitors



Magnetics



RF & Microwave Components



EMI/EMC Filters



Position Sensors & Slip Rings



Precision Mechanics

FROM STANDARD TO CUSTOM DESIGNS

Exxelia has earned international recognition in designing and manufacturing custom passive components that deliver the required performance for any application. As a high-end supplier, Exxelia is involved in most major programs in space, defense and civil aviation industries.

7 MARKETS



Civil aviation



Space



Defense



Transport & Energy



Telecom



Medical



Industry

10 COMPANIES, 1 BRAND

Eurofarad	Exxelia Technologies
Microspire	
N'Ergy	Exxelia Magnetics
Firadec	ExxeliaTantalum
Sic-Safco	Exxelia Sic Safco
Temex Ceramics	Exxelia Temex
Astema	Exxelia Maroc
Dearborn	Exxelia Dearborn
Raf Tabtronics	Exxelia Raf Tabtronics
DeYoung Mfg	Exxelia DeYoung

EXXELIA AT A GLANCE



1600 市本市有

Employees

ISO 9001 EN 9100 AS 9100 Certified Manufacturing Locations



Expertise since **1921**



EXXELIA WORLDWIDE

Exxelia is a global company with manufacturing sites strategically located to cover every continent. Three assembly plants are established in competitive manufacturing countries, enabling the group to provide cost-effective solutions. Thanks to

an extensive sales network covering more than 30 countries, Exxelia is able to provide prompt in-depth technical expertise throughout a project and remain close to its clients at all stages from design to production.

OUR APPROACH

Exxelia focuses its know-how on challenging markets that require high level of technicity and reliability. Our approach is based on three key principles:

FOCUS: serving a limited number of defined markets to deeply understand the needs of those markets.

INNOVATION: Provide new and creative value propositions combining the right products with the expected level of service.

RESPONSIVENESS: Anticipate the markets' needs and respond very quickly.



CERAMIC CAPACITORS



CERAMIC CAPACITORS:

The term «Ceramic capacitor» refers to the dielectric used to make capacitors. The type of ceramic used is a synthetic material obtained by submitting a mixture of carefully selected oxides to a high temperature treatment.

Multi-layer ceramic capacitors are made in the form of monolithic block and contain interleaved metal electrodes. These electrodes are alternately exposed on opposite sides of the package.

Their excellent temperature resistance, high volume/capacitance ratio, electrical properties and reliability make these components ideal for a wide range of fields of application including medical implants, aircraft flight controls, switch-mode power supply in harsh environments, core samplers for petroleum exploration, and space vehicles.

CUSTOM DESIGN CAPACITORS:

If you have the need for special capacitor designs, EXXELIA TECHNOLOGIES will be glad to make recommendations on how best to meet your application needs.



The rigid quality control exercised by EXXELIA TECHNOLOGIES on all its standard production is also applied to custom-fabricated film capacitors. Where necessary, special testing is done to verify requirements, such as low dielectric absorption, ultra-high insulation resistance, low dissipation factor, stability under temperature cycling or under specified environmental conditions, etc.





Feel free to contact EXXELIA TECHNOLOGIES with any request for specific interfaces, package size, characteristics.



		T°	Product range (space grade available in green)
		2°C	CEC / CNC
	Chips	-55°C+125°C	CEC Y (polymer termination)
		-5	CNC Y (polymer termination)
	sdic	.5°C	CER / CNR 14 - 2 - 12 - CEL / CNL 14 - 2 - 12
	Custom chips	–55°C +125°C	C 3 E - C 4 E - C 3 N - C 4 N
	Cust	-55	BPM 12 - BPM 22 - TBC 177 TBC 277 BPM 224 - BPM 24
			TCE 11 - TCE 13 - TCE 61 to TCE 64
dard	ss 1	25°C	TCE 50/60 - CC 05/06
Standard	Molded class 1	–55°C +125°C	TCE 52 to TCE 54
	Mold	-55	TCE 72 to TCE 80
			LA 1 to LA 5
			TCN 52 to TCN 55
	ss 2	<u></u> ک.د	TCN 72 to TCN 80
	Molded class 2	-55°C +125°C	TCN 19 - TCN 50/60 - TCN 30 - TCN 31 - TCN 61 to TCN 64
	Mold	-55	LA 6 A - LA 6 B
			CK 05 - CK 06
on netic	1. Chips	55°C+125°C	R14 to S47
Non magnetic	Rad.	–55°C+	S43 to S47
	bs		C 178 to 189 - C 278 to 289
	Chips		C 479 to 488
age	Stacks	ງ.5:	CS 181 to CS 188 - CS 281 to CS 288
High voltage		°C + 12	CS 481 to CS 488
Hig		-55	TCF 178 to 188-TCF 278 to 288 - TKD 179 to 185 - TKD 279 to 285
	Molded		TCK 179 to 188-TCK 279 to 288 - TCL 179 to 188 - TCL 279 to 288
			TCF 479 to 488 - TCK 479 to 488 - TCL 479 to 488
	Chips		R2225 to R45107
	Radial		R2225 to R8060
High capacitance	æ	J.27	TEP/TEV 53 to 65
apaci		-55°C +125°C	SC00 to SC18 - SV01 to SV07 - CNC31 to 34
High (Stacks	-55	CNC53 to CNC 65
			CEC53 to 65
	Block		TCN83 - TCN86 - TCN87
	Self prot. Mold. Chips Block	_55°C +250°C	CEC 203 to CEC 233 - CNC 203 to CNC 233 - CE/CN2X - CE/CN5X
are	Mold.	ں	TCE/TCN 201 to 204 - TCE/TCN 252 to 254
perat	prot.	+200°	TCE 212 to TCE 216 - TCN 212 to TCN 216
High temperature		–55°C +200°C	TCE 263 to TCE 266 - TCN 263 to TCN 266
High	Rad.		TCH 279 to TCH 285
	Chips/Rad. or ribbon leads Stacks Rad.	_55°C +215°C	SCT00 to SCT18
ors	n leads	ں	SPT 519
apacit	r ribbor	–55°C +125°C	CAW 54 to CAW 65
Power capacitors	Rad. o	–55°C	CEW 54 to CEW 65
8	Chips		CNW 32

Dielectric material	Capacitance	Voltage	For spac	ce grade Voltage	Tolerance	Use
NPO - 2C1 - X7R	1 pF ➡ 10 μF	16 V ➡ 1 000 V	1 pF 🖈 3.9 µF	10 V ⇒ 1 000 V	±1% ⇒ ±20%	
NPO	1 pF ➡ 180 nF	16 V ⇒ 1 000 V	1 pF ➡ 68 nF	10 V ➡ 100 V	±1% ⇒ ±20%	Precision, stability,
2C1 - X7R	10 pF ➪ 10 μF	16 V ⇒ 1 000 V	10 pF ⇒ 3.9 μF	10 V ➡ 100 V	±5% ⇒ ±20%	decoupling, SMD.
NPO - 2C1 - X7R	1 pF 🕏 270 nF	16 V ⇒ 100 V			±1% ⇒ ±20%	Low inductance, Low profile.
NPO - 2C1 - X7R	4.7 pF ⇒ 33 nF	25 V ⇔ 200 V			±1% ⇒ ±20%	Capacitance arrays.
NPO - X7R	10 pF ⇒ 4.7 μF	25 V ⇒ 500 V			±5% ⇒ ±20%	Feed through filters.
NPO - N150	0.5 pF ⇒ 47 nF	50 V ⇒ 100 V			±1% ⇒ ±20%	
NP0	1 pF 🕏 22 nF	50 V ⇒ 200 V			±1% ⇒ ±10%	Precision, stability,
NPO	1 pF ➡ 10 nF	63 V ⇒ 100 V			±0.5% ⇒ ±20%	epoxy resin molded, through hole components.
NP0	1 pF ➡ 100 nF	63 V ⇒ 200 V			±1% ⇒ ±20%	Axial & Radial leads.
Several	1 pF ➡ 680 nF	25 V ⇔ 63 V			±1% ⇒ ±20%	
2C1 - X7R	10 pF 🕏 470 nF	63 V ⇒ 500 V			±5% ⇒ ±20%	
2C1 - 2C2	22 pF ➡ 4.7 μF	50 V ⇔ 200 V			±10% ⇒ ±20%	Decoupling,
2C1	10 pF ➡ 2.2 μF	25 V ⇔ 250 V			±5% ⇒ ±20%	epoxy resin molded, through hole components.
201	100 pF ➪ 1 μF	25 V ➪ 63 V			±5% ⇒ ±20%	Axial and radial leads.
ВХ	10 pF ⇒ 1 μF	50 V ⇒ 200 V			±10% ⇒ ±20%	
X7R - NPO	10 pF ➡ 1 μF	63 V ⇒ 500 V			±1% ⇒ ±20%	Non magnetic components for Medical applications:
X7R - NPO	180 pF ➡ 1 μF	63 V ⇒ 500 V			±1% ⇒ ±20%	MRI systems and RF generators for MRI X-ray systems & power suppliers for X-ray
NPO - X7R	10 pF ➡ 39 μF	200 V ⇒ 10 000 V	10 pF ➡ 6.8 μF	250 V ➡ 10 000 V	±1% ⇒ ±20%	
N2200	22 pF ➡ 10 μF	200 V ⇒ 5 000 V	22 pF ➡ 10 μF	200 V ⇒ 5 000 V	±5% ⇒ ±20%	
NPO - X7R	1 nF ➡ 15 μF	1 000 V ⇒ 10 000 V			±10% ⇒ ±20%	Power supply, voltage multiplier, radars.
N2200	1.2 nF 🕏 47 μF	200 V ⇒ 5 000 V			±5% ⇒ ±20%	aeronautic space
NPO - X7R	10 pF 🕏 39 μF	200 V ⇒ 10 000 V	10 pF ➡ 6.8 μF	250 V ➡ 10 000 V	±5% ⇒ ±20%	• defense
NPO - X7R	10 pF 🕏 39 μF	200 V ⇒ 10 000 V	10 pF ⇒ 6.8 μF	250 V ➡ 10 000 V	±5% ⇒ ±20%	• railways
N2200	22 pF ➪ 10 μF	200 V ⇒ 5 000 V			±5% ⇒ ±20%	
X7R	47 nF 🕏 270 μF	50 V ⇒ 500 V			±10% ⇒ ±20%	
X7R	47 nF 🕏 270 μF	50 V ⇒ 500 V			±10% ⇒ ±20%	
NP0	10 nF ⇒ 6.8 μF	63 V ⇒ 500 V			±10% ⇒ ±20%	Power supply,
X7R	47 nF ➡ 400 μF	16 V ⇒ 500 V	1.2μF ⇒ 68 μF	16 V ➡ 25 V	±10% ⇒ ±20%	filtering, smoothing, decoupling. • aeronautic
X7R	100 nF 🕏 180 μF	50 V ⇒ 500 V	100 nF 🕏 180 μF	50 V ⇔ 500 V		• space • defense
NPO	10 nF 🕏 6.8 μF	63 V ⇒ 500 V	10 nF ➡ 6,8 nF	50 V ➪ 500 V	±10% ⇒ ±20%	
X7R	680 nF 🕏 120 μF	50 V ⇒ 500 V			±10% ⇒ ±20%	
NPO - X7R	1 pF ➪ 5.6 μF	16 V ⇒ 100 V			±1% ⇒ ±20%	
NP0 - X7R	1 pF 🖈 1.5 μF	50 V ⇒ 100 V			±1% ⇒ ±20%	High temperature,
NPO - X7R	10 pF ⇒ 3.9 μF	50 V ⇒ 100 V			±5% ⇒ ±20%	SMD high capacitance
NPO - X7R	1 pF ➪ 3.3 μF	25 V ⇒ 500 V			±2% ⇒ ±20%	high voltage self protected
X7R	100 pF 🕏 2.7 μF	200 V ⇒ 3 000 V			±10% ⇒ ±20%	oil drilling, motor control.
X7R	47 nF 🕏 400 μF	16 V ⇒ 500 V			±10% ±20%	
NP0	10 pF ⇔ 5600 pF	550 V ⇔ 6 300 V			±5% ⇒ ±10%	HF - VHF transmission,
P100	1 pF ➡ 10 nF	1 000 V ⇒ 3 600 V			±5% ⇒ ±10%	antenna tuning.
NP0	4.7 pF ➡ 15 nF	1 000 V ⇒ 3 600 V			±5% ⇒ ±10%	• low losses • high current
X7R	10 nF ⇒ 1 μF	100 V ⇒ 300 V			±10% ⇒ ±20%	• high voltage

High-Q CAPACITORS

Wide choice of ceramic multi-layer and single layer capacitors mostly intended for applications requiring low losses (low ESR - high Q factor) in a given range of working frequencies and for a specified DC or RF voltage. Capacitors are available either as "chip" or with leads or ribbons. **EXXELIA** TEMEX is also providing special connections for customized solutions.

The very well known "High Q" series CHA (0505) and CHB (1111) widely used in the world are completed with the "super High Q SHA & SHB" ultra-stable NPO dielectric for a direct superseding when needed. EIA sizes 0402 (SHL) 0603 (SHS) 0805 (SHF) 1206 (SHN) and 1210 (SHT) 250 to 1000 V rated versus selected capacitance are also available. These sizes are mainly used in base stations, power amplifiers, filters and broadcasting.

Frequency range : some MHz up to several GHz. All ranges are RoHS and are also available with non-magnetic terminations.

For High power, high Voltage applications (MRI, NMR, RF generators for laser, plasma applications, power filters), EXXELIA TEMEX propose CP and CL series with two stable dielectric types (NPO and P9O) with voltages ranging from 1000 to 7000 V (special range for 5 000 Vrms or more guaranteed). Special assemblies with ribbons are available and can be studied with customers versus actual design consideration.

Non-magnetic terminations also available.







	T°	Туре	Product range	Temperature coeff.	Extended temp.*	Capacitance	Tolerance *	Standard voltage *	Use
ø,		CHA	0505	P100 (100 ± 30ppm/°C)		0.1 ⇒ 100 pF		250 V	Callular hass station amplifier MDI
		СНВ	1111	P100 (100 \pm 30ppm/°C)	Up to +175°C	0.2 ⇒ 1 000 pF		500 V	Cellular base station amplifier, MRI
		SHA	0505	NPO $(0 \pm 30 \text{ppm/°C})$		0.2 ⇒ 100 pF		250 V	
citor		SHB	1111	NPO $(0 \pm 30 \text{ppm/°C})$	Up to +175°C	0.3 ⇒ 1 000 pF		500 V	
Capacitors	ړ	SHL	0402	NPO $(0 \pm 30 \text{ppm/°C})$		0.1 ⇒ 33 pF		200 V	
	+125°C	SHS	0603	NPO $(0 \pm 30 \text{ppm/°C})$		0.1 ⇒ 100 pF	±0.05pF	250 V	Cellular base station equipment,
ow E	. J.25	SHF	0805	NPO $(0 \pm 30 \text{ppm/°C})$		0.3 ⇒ 220 pF	±10%	250 V	Broadband,
RF MLCC, low ESR	Ţ,	SHN	1206	NPO $(0 \pm 30 \text{ppm/°C})$		0.5 ⇒ 220 pF		500 V	Point to point/ multi-point radios, RF generators
M.		SHT	1210	NPO $(0 \pm 30 \text{ppm/°C})$		1 ⇒ 1 000 pF		500 V	, and the second
Œ		SHD	0711	NPO $(0 \pm 30 \text{ppm/°C})$	Up to +175°C	0.5 ⇒ 100 pF		500 V	
		SHR	0709	NPO $(0 \pm 30 \text{ppm/°C})$	Up to +175°C	0.5 ⇒ 100 pF		500 V	
		NHB	1111	NPO $(0 \pm 30 \text{ppm/°C})$	Up to +175°C	0.3 ⇒ 100 pF		500 V	
	ړ	CPX	2225	P100 (100 ±30)		0.5 ⇒ 2 700pF		2 500 V	
	+125°C	CPE	4040	P100 (100 \pm 30)		1 ➪ 10 000 pF	±0.1pF	3 600 V	RF power amplifier,
	. 22°C	CLX	2225	NP0 (0 ± 30)		0.3 ⇒ 2 700 pF	±20%	2 500 V	Plasma chamber, MRI coils
_ °	i,	CLE	4040	NP0 (0 ±30)		1 ⇒ 10 000 pF		3 600 V	

* Depending on capacitance value. Available extended voltage on request.

MICROWAVE COMPONENTS

FREQUENCY TUNING ELEMENTS:

Those special elements are intended for adjusting a circuit made /using cavities: inserted in the cavity, their capacitive, resistive or inductive characteristics are used to tune the filter accordingly. The "self-locking" system primordial for stability in application when filters are located in outdoor cabinets High Reliability versions are available (space). Custom design upon request.



DIELECTRIC TRIMMERS:

Ceramic dielectric trimmers allows a lot of combinations (capacitance ranges, voltages, temperature coefficient and also mounting methods). "Thin-Trim®, Ceratrim®, Chip trim®" are widely used for circuit trimming with high stability. Most of them are SMD and are delivered on tape, are RoHS, and can also be provided in non magnetic version.

Air dielectric trimmer capacitors are designed specifically for RF applications with concentric tubular design. They meet MIL-C-14 409 D, and ESA/SCC n°3010, and are RoHS compliant. They are ideal for applications such as mobile radios, aerospace communications, crystal oscillators and filters, radar and numerous other space, military and industrial applications.



Sapphire dielectric trimmers High "Q" characteristics, High voltage and various mechanical versions, make ideally suited to power applications in filters and high power amplifiers. They can be also offered in non-magnetic version for medical applications.

FERRITE MATERIALS:

Mostly intended for isolator & circulator widely used in radio-communication systems, Ferrite are offered in disk, triangle or custom-designed dimensions. They

are based on Temex-Ceramics formulation, providing low △H propitious to IMD reduction. Their combination with selected dielectric material allows a choice of FDA apparatus, of repute to save space in isolator/circulator.



RESONATORS:

Several dielectric constant ranging www 24 to 78, provide High "Q" factor for applications 1.5 GHz to 100 GHz through materials (E2000 to E7000).

Wide range of applications in DRO's mass production for satellite reception LNB's, radio-communication, Industrial (motion detection sensor), automotive (anticollision radar) etc... Combination of resonators and tuning elements for cavity filters adjustment on request.

Coaxial resonators are generally used in filters, duplexers, CRO's and VCO's applications within a broad range of frequencies: 300 MHz to 6 GHz. They are provided with several dimensions: 2 x 2 to 12 x 12 mm, allowing the best compromise between impedance, "0" factor and resonant frequency.



TANTALUM CAPACITORS

Due to technology used and the continuous evolution of tantalum powder, tantalum capacitors offer the highest charge per unit of volume combined with high reliability and durability.

They are used in consumer goods and more specialized niches including space vehicles, aircraft electronics, weapons and rail transport.

 $\textbf{EXXELIA} \, \textbf{TANTALUM} \, \text{develops both solid and wet tantalum capacitors}.$

Feel free to contact EXXELIA TANTALUM with any request for specific interfaces, package size, characteristics.



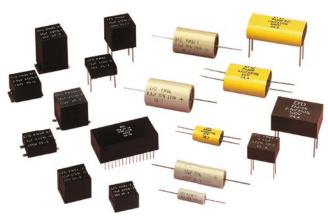
		Product range	Detail specification	Capacitance	Voltage	Operating Temperature	Main features
		CT 79 (T3T - 40AW) CT 79 SMD	CECC 30202-005/001/801 ESCC 3003/005	1.7μF ➡ 1 200μF	6 V ⇒ 150 V	−55°C+125°C	High ripple current.
		CT 79E (ST3T - 40AW) CT 79E SMD	CECC 30202-005/001/801 ESCC 3003/005	5.6 μF 🕏 2 200 μF	6 V ⇒ 150 V	−55°C+125°C	High ripple current. Extended range (CT 79E / SMD).
	es - Axial types	CT 79 HT200 - CT 79E HT200 ST 79 HT200	CECC 30202-005/001/801	1.7 μF ➡ 2 200 μF	6 V ➡ 150 V	−55°C+200°C	High capacitance. High Temperature.
	alum cas Ilaris ed	ST 79	DSCC - DWG No. 93026 ESCC 3003 / 006	90μF ⇒ 1800μF	25 V ⇒ 125 V	−55°C+125°C	High capacitance.
tors	Tanta Po	WT 82	-	33µF ⇒ 82µF	160 V 🕏 170 V	−55°C+70°C	High voltage.
capaci		WT 83	-	150μF ⇒ 10 000μF	10 V ⇒ 125 V	−55°C+125°C	Extended Capacitance - Enhanced performance High reliability design.
Wet tantalum capacitors		WT 84	MIL-PRF-39006/33 - DSCC DWG NO 93026	10 μF ⇔ 1800μF	25 V ➡ 125 V	−55°C+125°C	Extended Capacitance - Enhanced performance High reliability design.
/et tan	* *	CT 9 - CT 9CR (TLT) CT 9E - CT 9ECR (STLT)	CECC 30202-004	3μF ⇔ 2 200μF	6.3 V ⇒ 150 V	−55°C+125°C	Silver case. Glass metal seal. Extended range (CT 9E / 9ECR).
>	*	CT 4 (TL) / CT 4E (STL)	CECC 30202-003 (CT4) BS 9073 F008 / F032 (CT 4E)	1.7μF ⇔ 2 200μF	6 V ⇒ 150 V	−55°C+125°C	Silver case. Seal and resin sealing. Extended range (CT 4E).
	cases	SPE0844 / SPE0844S	BS CECC 30202-009 (SPE0844) CECC 30202-005 / 001 / 801	27 μF ➡ 6 000 μF	6 V ⇒ 375 V	−55°C+125°C	
	moulded cases ised types	AP 31	-	168μF ⇒ 30 000μF	10 V ⇒ 150 V	−55°C+125°C	Parallel, serie connected. Reverse voltage. High ripple current.
	o 💳	AP 41	-	330 μF ➡ 40 000 μF	10 V ⇒ 150 V	−55°C+125°C	(The module incorporate CT 79 / CT 79 E)
	Stackabl	AS 31	-	27 μF ⇒ 733 μF	150 V ➡ 450 V	−55°C+125°C	
	v	CTS 1 (SI 125)	CECC 30201-001 / 002 / 801 CEI-300201-FR0001	0.1μF ⇔ 330μF	6.3 V ⇒ 125 V	−55°C+125°C	Standard range. General purpose +125°C.
	ed metal cases sed types	CTS 13 (SI 85)	CECC 30201-005	0.1μF ➡ 330μF	6.3 V ⇒ 63 V	−55°C+85°C	Standard range. General purpose +85°C.
	aled met rised typ	CTS 32 (IS 125)	CECC 30201-019	1μF ⇔ 330μF	6.3 V ⇒ 63 V	−55°C+125°C	Standard range. High surge current. Reverse voltage.
	cally ser	CTS 23 (SIS 125)	CECC 30201-025	0.1μF ➡ 1 200μF	6.3 V ⇒ 63 V	−55°C+125°C	Extended range. General purpose.
	Hermeti Axi	CTS 33 (SISFR 125)	CECC 30201-026	0.1μF ➡ 1 000μF	6.3 V ⇒ 63 V	−55°C+125°C	Extended range. Low leakage current.
		CTS 21 (SIZR 125) CTS 21E (SISZR 125)	CECC 30201-040 ESCC 3002 / 003 (CTS 21E)	5.6μF ➡ 1 000μF	6.3 V ⇒ 63 V	−55°C+125°C	Low ESR. High ripple current. High surge current. Extended range (CTS 21E).
tors	*	CTS 20 (NSI 125) CTS 20E (SNIS 125)	CECC 30201-022 (CTS 20)	0.22μF ⇒ 560μF	6.3 V ⇒ 63 V	−55°C+125°C	Cathode to cathode coupling of two CTS 1 or 23.
tantalum capacitors	d cases olarised	CTS 41 (SBM 41) CTS 41RSE (FR 125)	CECC 30201-037	0.1μF ➡ 150μF	6.3 V ⇒ 50 V	−55°C+125°C	Miniature 125°C. High surge current. Reverse voltage. Low ESR (CTS 41RSE).
alum (Moulde Radial F	CTS 4 (SBM R)	CECC 30201-003	0.1μF ➪ 150μF	6.3 V ⇒ 50 V	−55°C+85°C	Miniature. General purpose +85°C.
		CTC 3 / CTC 3E	CECC 30801-009 / 801 (CTC 3)	0.1μF ➡ 680μF	4 V ⇒ 50 V	−55°C+125°C	Standard chip size. General purpose. Extended range (CTC 3E).
Solid	ζ0.	CTC 4	CECC 30801-011	0.1μF ➪ 100μF	6.3 V ⇒ 50 V	−55°C+125°C	Standard chip size. General purpose. High surge current.
	SMD ised type	CTC 4 RSE	-	4.7μF ⇒ 1 000μF	6.3 V ⇒ 50 V	−55°C+125°C	Low ESR. High ripple current. High surge current.
	Moulded cases - SM ce mount - Polarisec	CTC 21 / CTC 21E	CECC 30801-013 ESCC 3012/002 (CTC 21) 003 (CTC 21E)	5.6 μF 🖈 680 μF	6.3 V ⇒ 100 V	-55°C+125°C	Low ESR. High ripple current. High surge current. Extended range (CTC 21E).
	oulded o	CTC 23	-	15μF ⇒ 1 000μF	6.3 V ⇒ 63 V	−55°C+125°C	General purpose. Extended range.
	M Surface	CTC 42 / CTC 42E	-	12 μF ➡ 1 500 μF	6.3 V ⇒ 80 V	-55°C+125°C	Two CTC 21 assembly. Extended range (CTC 42E).
		CTP 21	-	22μF ⇒ 560μF	16 V ➡ 100 V	−55°C+105°C	Very low ESR. High ripple current. High surge current. No thermal ignition.
		CTP 42	-	47μF ➡ 1 200μF	16 V ➡ 100 V	−55°C+105°C	Two CTP 21 assembly.

^{*} Hermetically sealed metal cases - Axial leads - Non polarised types



^{**} Silver cases - Axial leads - Polarised types

FILM CAPACITORS



PLASTIC FILM CAPACITORS:

EXXELIA TECHNOLOGIES and EXXELIA DEARBORN film capacitor product lines include a wide array of catalog products using state of the art technologies combined with the latest developments in dielectric films (including polyester, polypropylene, P.P.S, and teflon). Kraft/paper, foil capacitor, and metallized film capacitor products are available. Defense film capacitors are tested and qualified to defense standards, with more than 30 defense qualified products.

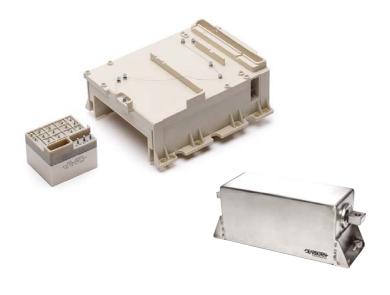
A wide selection of packaging designs are available such as SMD film-wrapped, pre-molded epoxy cases, and hermetically sealed metal cases.



CUSTOM DESIGN CAPACITORS:

EXXELIA GROUP offers a wide range of custom design capabilities with respect to Temperature, Capacitance, Frequency and Voltage requirements.

Strong heritage, high reliability and quality of EXXELIA GROUP make them perfectly suitable for all challenging environmental conditions and specific interfaces.





	T (°C)	Product range (space grade available in green)
	55°C)	PM 89-PM 90 (S)-PM 94(S)
Polyester for or S.M.P.S.	-55°C +125°C (+155°C)	PM 96(S) - PM 96 T(S) - MKT(S)
Polyester or or S.M.P.	: +125	PM 948(S) - PM 907(S)
_	–55°ر	PHM 912
		PM 50 - PM 60
		PM 7 - PM 12 - PM 720 - PM 730
		MPA HT - MRA HT
		BIK-X2/Y - BIK P-X/Y - BIK CR
	ວ.ເ	205P
Ę.	−55°C +125°C	218P
Polyester	-55	410P
2		430P
		431P
		442P
		CP53 / 54 / 55
	-65 +125	132P
	-40 +85	409P
		A 64 S4 (T) - A 74 S4 (T) - PMR 4 (T)
_		MPA 4 - MKB 4
Sulfide (P.P.S. suffix T)		KCP 4 UA T
P.S. SI		KSP 4 UA T
ide (F		K1PE T
	J.2;	KM 501-601(T) - KM 50-60(T)
nylen	-55°C +12º	KM 111 (T)(S)
olyphe	-26	KM 311-21-711-7 (T)
te / Pc		KM 78 - 82 - 90 - 97 (T)
rbona		PMR 64 (T) - PMA 64 (T)
Polycarbonate/ Polyphenylene		PM 67 (T) - PM 72 (T)
		KM 94 (S)
		KM 915
		810P
		820P
(P.P.S.		832P
ulfide	25°C	842P
ene Si	– 55°C +125°C	859P
Polyphenylene Sulfide (P.P.S.)		860P
Polyp		882P
		PRF-83421/06
'' a	U U	880P
polys	_55°C +85°C	PLS 3 - PLS 5 - PLS 7 - PLS 8
ligh Itage	–55°C +125°C	HT 72 - HT 77
_	17	HT 96 - HT 78(P)(S) - HT 86 (P)(S) - HT 97(P)(S)

Measured polymere (PE1) 20 pt 25 km ± 20	Dielectric	Capacitance	acitance Tolerance Voltage Qualification		Use	
Polymeter DCT 30 n P		8.2 nF 🖈 150 µF	±5% ⇒ ±20%	50 V ⇔ 630 V		
Memilined placeficities 1.8 µ F ← 88 µ F		33 nF ⇒ 100 μF	±5% ⇒ ±20%	25 V ➡ 630 V	Acc. ESA	High frequency switch mode power supplies, SMD. • defense
1 中		22 nF ➡ 180 μF	±10 % ±20 %	63 V ➡ 1250 V	ESA / ESCC	
Metallized polygotest 82 pf や 10 μF	Metallized plastic film	1.8 μF ➡ 68 μF	\pm 10 % \pm 20 %	250 V ⇒ 1000 V	in house	
Metallized polygonary 1 n ← 4.7 μF		1 nF 🖈 22 μF	±5%	40 V ➡ 630 V	CECC / IEC	
Metallized polyster	Metallized polyester	82 pF ➡ 10 μF	±5% ⇒ ±20%	63 V ➡ 630 V	CECC / IEC	
Metallized polyproughese		1 nF 🕏 4.7 μF	±5%	1000 V ⇒ 15000 V	in house	Standard applications.
1 n		1 nF 🖈 6.8μF	±5%	400 V _{DC} - 250 V _{AC}	in house	
1 nF ← S.D.µF		1 nF 🕏 0.5μF	±20% ⇒ ±10%	2 000 ➡ 10 000 V		High Voltage
Polyester (PE.T.) 10 nF ↔ 15.0µF		1 nF ➡ 12.0 μF	±20% ⇒ ±5%	100 ➡ 400 V	MIL QPL	
Polygester (PE.T.) 10 nF Φ 10 μF		1 nF 🖈 5.0 μF	+20% −10% ⇒ ±10%	50 ⇔ 600 V		
10 κF + 100 μF		1 nF 🖈 10.0 μF	±20% ⇒ ±5%	63 ➡ 16 000 V		High Voltage
SOR = Φ 10 OμF +20 - 10% ± 10% 100 Φ 1 000 V 1 nF Φ 1 OμF +20% ± 10% 100 Φ 1 000 V MIL OPL 1 nF Φ 1 OμF +20% ± 10% 50 Φ 1 000 V MIL OPL O 10 UF Φ 0.5 μF +20% +10% 50 Φ 1 000 V F62 102 Metall polycarbo / PPS 1 nF Φ 33 μF ± 1 % Φ ± 20 % 40 V Φ 630 V NF F62 102 Metallized polygester 1 nF Φ 22 μF ± 5 % Φ ± 20 % 40 V Φ 630 V NF F62 102 Film-foll / PPS 75 nF Φ 727 nF ± 2 % ± 5 % 630 V Φ 1000 V Acc. NF F62 102 Metallized PPS 10 nF Φ 0.2 μF ± 1 % Φ ± 20 % 400 V Φ 1500 V Acc. NF F62 102 Metallized PPS 10 nF Φ 0.2 μF ± 1 % Φ ± 20 % 400 V Φ 630 V NF F62 102 Metallized PPS 10 nF Φ 22 μF ± 1 % Φ ± 20 % 400 V Φ 630 V NF F62 102 Metallized PPS 1 nF Φ 10 μF ± 1 % Φ ± 20 % 400 V Φ 630 V EECC Metallized PPS 1 nF Φ 22 μF ± 1 % Φ ± 20 % 400 V Φ 630 V EECC Metallized PPS 1 nF Φ 10 μF ± 1 % Φ ± 20 % 400 V Φ 630 V EECC APO pF Φ 22 μF ± 1 % Φ ± 20 % 400 V Φ 630 V EECC APO pF Φ 22 μF ± 1 % Φ ± 20 % 400 V Φ 630 V in house 1 nF Φ 10 μF ± 1 % Φ ± 20 % 400 V Φ 630 V in house 1 nF Φ 10 μF ± 1 % Φ ± 20 % 400 V Φ 630 V in house 1 nF Φ 10 μF ± 1 % Φ ± 20 % 400 V Φ 630 V in house 1 nF Φ 10 μF ± 1 % Φ ± 20 % 400 V Φ 630 V in house 1 nF Φ 10 μF ± 1 % Φ ± 20 % 400 V Φ 630 V in house 1 nF Φ 10 μF ± 1 % Φ ± 20 % 5 0 Φ 400 V ESA/ESPC (EPPL) High stability, SMD. Metallized PPS 1 nF Φ 10 μF ± 1 % Φ ± 20 % ± 5 % Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ Φ	Polyester (P.E.T.)	10 nF 🖈 15.0 μF	±20% ⇒ ±5%	63 ⇔ 630 V		
1nF ← 1.0µF		10 nF 🖈 10.0 μF	±20% ➡ ±5%	63 ⇔ 400 V		AC / DC Current
Metallized polycarbo / PPS 1 n ∈ 9 3 μ		50 nF 🖈 10.0 μF	+20 −10% 🕏 ±10%	100 ➡ 1 000 V		
Metall polycarbo / PFS. 1 n f ⇔ 33 µF ±1 % ⇔ ±20 % 40 ∨ ⇔ 630 ∨ NF F62 102 Metallized polyester 1 n f ⇒ 22 µF ±5 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ NF F62 102 Film-foil / PFS. 25 n f ⇔ 727 n f ±2 % ±5 % 630 ∨ ⇔ 1000 ∨ Acc. NF F62 102 Metallized PFS. 10 n f ⇔ 0.2 µF ±1 % ⇒ ±20 % 400 ∨ ⇒ 630 ∨ NF F62 102 Metallized PFS. 10 n f ⇒ 0.2 µF ±1 % ⇒ ±20 % 400 ∨ ⇒ 630 ∨ CECC Metallized PFS. 1 n f ⇒ 22 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ CECC 1 n f ⇒ 22 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ CECC 1 n f ⇒ 22 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ CECC 1 n f ⇒ 10 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ CECC 1 n f ⇒ 10 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ in house 1 n f ⇒ 15 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ in house 1 n f ⇒ 12 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ in house Metallized PPS. 1 n f ⇒ 12 µF ±1 % ⇒ ±20 % 40 ∨ ⇒ 630 ∨ in house 1 n f ⇒		1 nF 🖈 1.0 μF	+20% −10% ⇒ ±10%	100 ➡ 1 000 V	MIL QPL	
Metallized polyester 1 n		0.10μF ⇒ 0.5μF	+20% −10% ⇒ ±10%	50 ➡ 1 000 V		EMI Suppression
Film-foil / PPS $25 \text{ n} \text{ F} \Leftrightarrow 727 \text{ n} \text{ f}$ $\pm 2 \text{ X} \pm 5 \text{ X}$ $630 \text{ V} \Rightarrow 1000 \text{ V}$ Acc. NF F62 102 Safety capacitors for signalling and others railways applications. Film-foil / PPS $10 \text{ n} \text{ F} \Leftrightarrow 0.2 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \Leftrightarrow 630 \text{ V}$ NF F62 102 Metallized PPS $1 \text{ n} \text{ F} \Leftrightarrow 22 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \Leftrightarrow 630 \text{ V}$ CEEC Metallized PPS $1 \text{ n} \text{ F} \Leftrightarrow 10 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \Leftrightarrow 630 \text{ V}$ CEEC Metallized PPS $1 \text{ n} \text{ F} \Leftrightarrow 10 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \Leftrightarrow 630 \text{ V}$ CEEC Metallized PPS $1 \text{ n} \text{ F} \Leftrightarrow 10 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \Leftrightarrow 630 \text{ V}$ in house $1 \text{ n} \text{ F} \Leftrightarrow 10 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \Leftrightarrow 208 \text{ V}$ in house $1 \text{ n} \text{ F} \Leftrightarrow 12 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \Leftrightarrow 208 \text{ V}$ in house $1 \text{ n} \text{ F} \Leftrightarrow 1.2 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \approx 208 \text{ V}$ in house $1 \text{ n} \text{ F} \Leftrightarrow 1.2 \text{ µF}$ $\pm 1 \text{ X} \Leftrightarrow \pm 20 \text{ X}$ $400 \text{ V} \approx 208 \text{ V}$ in house 1 n	Metall. polycarbo. / P.P.S.	1 nF 🖈 33 μF	±1 % ⇒ ±20 %	40 V ➡ 630 V	NF F 62 102	
Film-foil / P.P.S. 10 n F Φ 0.2 μF	Metallized polyester	1 nF 🕏 22 μF	±5% ⇒ ±20%	40 V ➡ 630 V	NF F 62 102	
Film-foil / P.P.S. 10 n F φ 0.2 μF	Film-foil / P.P.S.	7.5 nF ⇒ 77.7 nF	±2 % ±5 %	630 V ⇒ 1000 V	Acc. NF F 62 102	
	Film-foil / P.P.S.	10 nF 🕏 0.2 μF	±1 % ➡ ±20 %	400 V ➡ 1500 V	Acc. NF F 62 102	5
Metallized polycarbonate / P.P.S. $1 \text{ nF} \Leftrightarrow 10 \mu\text{F}$ $\pm 1 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $40 \text{ V} \Leftrightarrow 400 \text{ V}$ ESA [EPPL] / CECC Precision capacitors (Capacitance stability, low tolerance) (Capacitance stability, control electronics). $1 \text{ nF} \Leftrightarrow 10 \text{ µF}$ $\pm 1 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $40 \text{ V} \Leftrightarrow 208 \text{ V}$ in house $1 \text{ nF} \Leftrightarrow 15 \text{ µF}$ $\pm 1 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $40 \text{ V} \Leftrightarrow 208 \text{ V}$ in house $1 \text{ nF} \Leftrightarrow 1.2 \text{ µF}$ $\pm 1 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $40 \text{ V} \Leftrightarrow 208 \text{ V}$ in house $1 \text{ nF} \Leftrightarrow 1.2 \text{ µF}$ $\pm 1 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $40 \text{ V} \Leftrightarrow 208 \text{ V}$ in house $1 \text{ nF} \Leftrightarrow 1.2 \text{ µF}$ $\pm 1 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $40 \text{ V} \Leftrightarrow 208 \text{ V}$ in house $1 \text{ nF} \Leftrightarrow 1.2 \text{ µF}$ $\pm 1 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $40 \text{ V} \Leftrightarrow 208 \text{ V}$ ESA/ESCC (EPPL) High stability, SMD. $1 \text{ nF} \Leftrightarrow 1.0 \text{ µF}$ $\pm 20 \text{ k} \Leftrightarrow \pm 20 \text{ k}$ $250 \text{ V}_{0C} \Leftrightarrow 630 \text{ V}_{0C}$ AC Filtering $1 \text{ nF} \Leftrightarrow 1.0 \text{ µF}$ $\pm 20 \text{ k} \Leftrightarrow \pm 18 \text{ k}$ $50 \Leftrightarrow 400 \text{ V}$ MIL OPL Polyphenylene Sulfide (PPS.) $10 \text{ nF} \Leftrightarrow 15.0 \text{ µF}$	Metallized P.P.S.	10 nF 🕏 3.3 μF	±1 % ⇒ ±20 %	400 V ⇒ 630 V	NF F 62 102	
Metallized polycarbonate / P.P.S. 1 n F \Leftrightarrow 22 μF ± 1 % \Leftrightarrow ± 20 % 40 V \Leftrightarrow 630 V CECC (Capacitance stability, low tolerance) Measurement, control electronics. AC filtering (400 Hz and others). 1 n F \Leftrightarrow 10 μF ± 1 % \Leftrightarrow ± 20 % 40 V \Leftrightarrow 208 V in house 1 n F \Leftrightarrow 15 μF ± 1 % \Leftrightarrow ± 20 % 40 V \Leftrightarrow 208 V in house 1 n F \Leftrightarrow 1.2 μF ± 1 % \Leftrightarrow ± 20 % 40 V \Leftrightarrow 208 V in house Metallized P.P.S. 1 n F \Leftrightarrow 1.2 μF ± 1 % \Leftrightarrow ± 20 % 250 V _{DC} \Leftrightarrow 630 V _{DC} 150 V _{AC} AC Filtering 1 n F \Leftrightarrow 1.2 μF ± 5 % \Leftrightarrow ± 20 % 250 V _{DC} \Leftrightarrow 630 V _{DC} 150 V _{AC} AC Filtering 1 n F \Leftrightarrow 1.0 μF ± 20 % \Leftrightarrow ± 5% 50 \Leftrightarrow 400 V MIL 0PL 1 n F \Leftrightarrow 1.0 μF ± 10 % \Leftrightarrow ± 2% 50 \Leftrightarrow 200 V MIL 0PL Poluphenylene Sulfide (P.P.S.) 10 n F \Leftrightarrow 10.0 μF ± 20 % \Leftrightarrow ± 5% 80 \Leftrightarrow 440 V _{RMS} MIL 0PL Precision capacitors Low TCC 1 n F \Leftrightarrow 22 μF ± 10 % \Leftrightarrow ± 2% 200 V 1 n F \Leftrightarrow 22 μF ± 10 % \Leftrightarrow ± 2.8 200 V 1 n F \Leftrightarrow 22 μF ± 10 % \Leftrightarrow ± 2.8 50 \Leftrightarrow 400 V		1 nF ➡ 22 μF	±1% ⇒ ±20%	40 V ➡ 630 V	CECC	
Metallized polycarbonate / P.P.S.		1 nF ⇒ 10 μF	±1% ⇒ ±20%	40 V ⇒ 400 V	ESA (EPPL) / CECC	
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	Metallized	1 nF 🕏 22 μF	±1% ⇒ ±20%	40 V ➡ 630 V	CECC	(Capacitance stability, low tolerance)
	polycarbonate / P.P.S.	1 nF ➡ 10 μF	±1% ⇒ ±20%	40 V ⇒ 208 V	in house	, and the second
		470 pF ⇔ 22 μF	±1% ⇒ ±20%	40 V ➡ 630 V	in house	, oog (o a a a a
Metallized P.P.S.		1 nF ⇒ 15 μF	±1% ⇒ ±20%	40 V ⇒ 208 V	in house	
1.5 nF \Rightarrow 2.7 μF	Motallizad DDC	1 nF 🕏 1.2 μF	±1% ⇒ ±20%	40 V ⇒ 100 V	ESA/ESCC (EPPL)	High stability, SMD.
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Metallizeu F.F.S.	1.5 nF ➡ 2.7 μF	±5% ⇒ ±20%			AC Filtering
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		1 nF 🕏 1.0 μF	±20% ⇒ ±5%	50 ⇔ 400 V		
Polyphenylene Sulfide [P.P.S.]		10 nF 🕏 15.0 μF	±10% ⇒ ±1%	50 ⇔ 400 V	MIL QPL	
Polyphenylene Sulfide (P.P.S.) 10 nF \Rightarrow 10.0 μF ±20% \Rightarrow ±5% 126 \Rightarrow 250 V _{RMS} MIL 0PL Precision capacitors Low TCC 10 nF \Rightarrow 10.0 μF ±20% \Rightarrow ±5% 126 \Rightarrow 250 V _{RMS} MIL 0PL 1 nF \Rightarrow 0.22 μF ±10% \Rightarrow ±2% 200 V 1 nF \Rightarrow 22 μF ±10% \Rightarrow ±0.25% 30 \Rightarrow 400 V MIL 0PL 4.7 nF \Rightarrow 10.0 μF ±10% \Rightarrow ±2% 50 \Rightarrow 400 V		1 nF ➡ 10.0μF	±10% ⇒ ±2%	63 ⇔ 400 V		
Sulfide (P.P.S.)		10 nF 🕏 15.0 μF	±10% ⇒ ±2%	50 ⇔ 200 V		
1 nF − 0.22 μF ±10% \Rightarrow ±2% 200 V 1 nF \Rightarrow 22 μF ±10% \Rightarrow ±0.25% 30 \Rightarrow 400 V MIL 0PL 4.7 nF \Rightarrow 10.0 μF ±10% \Rightarrow ±2% 50 \Rightarrow 400 V		10 nF 🕏 10.0 μF	±20% ⇒ ±5%	80 ⇒ 440 V _{RMS}	MIL QPL	
$1 \text{ nF} \Rightarrow 22 \text{ μF}$ $\pm 10\% \Rightarrow \pm 0.25\%$ $30 \Rightarrow 400 \text{ V}$ MIL QPL $4.7 \text{ nF} \Rightarrow 10.0 \text{ μF}$ $\pm 10\% \Rightarrow \pm 2\%$ $50 \Rightarrow 400 \text{ V}$		10 nF ⇒ 10.0 μF	±20% ⇒ ±5%	126 ⇔ 250 V _{RMS}	MIL QPL	
$4.7 \text{nF} \Rightarrow 10.0 \mu\text{F}$ $\pm 10\% \Rightarrow \pm 2\%$ $50 \Rightarrow 400 \text{V}$		1 nF – 0.22 μF	±10% ⇒ ±2%	200 V		
		1 nF ➡ 22μF	±10% ⇒ ±0.25%	30 ⇔ 400 V	MIL QPL	
Polystyrene + foil 10 pF \Rightarrow 1 μ F \pm 1 % \Rightarrow \pm 5 % 63 V \Rightarrow 500 V CCTU/CECC Filtering, frequency tuning.		4.7 nF ⇒ 10.0 μF	±10% ⇒ ±2%	50 ⇔ 400 V		
	Polystyrene + foil	10 pF ➡ 1 μF	±1% ⇒ ±5%	63 V ⇒ 500 V	CCTU/CECC	Filtering, frequency tuning.
Composite resin impregnated 100 pF \Rightarrow 4.7 μ F \pm 5 % \Rightarrow \pm 20 % 630 V \Rightarrow 25 000 V in house High voltage filtering. • defense	resin impregnated	100 pF ⇒ 4.7 μF	±5 % ⇒ ±20 %	630 V ⇒ 25 000 V		• defense
Reconstituted mica resin impregnated $100 \text{ pF} \Rightarrow 2.2 \mu\text{F}$ $\pm 5 \% \Rightarrow \pm 20 \%$ $630 V \Rightarrow 20 000 V$ $ESA/ESCC \text{ (DPL HT96)} \\ Acc. ESA/ESCC \text{ (HT97)}$ • aeronautic • space		100 pF ⇒ 2.2 μF	±5%	630 V ⇔ 20 000 V		

FILM CAPACITORS

EXXELIA TECHNOLOGIES and **EXXELIA** DEARBORN film capacitors have exceptional stability, low-loss, long life, and high reliability. They are exceptional for pulse/storage, DC link, energy discharge, and custom applications.

MICA CAPACITORS:

This natural mineral insulator has outstanding dielectric properties that are ideal for long-life high-stability capacitors with low loss at all frequencies, and high dielectric strength. This type of capacitor is used particularly for high frequency and delay line applications, oscillating circuits, emission devices and calibrators.



	(°C)	Product range (space grade available in green)	Dielectric	Capacitance	Tolerances	Voltage range	Qualification	Use
9		PP 04 - PP 05	Metallized polypropylene	330 pF ⇒ 6.8 µF	±5% ±10%	250 V ⇒ 2 500 V	in house	High current pulses, protection circuit high frequencies.
pyler	(+105)	PP 3 A - PP 3 M PR 3 A - PR 3 M	Metallized polypropylene+foil	680 pF ⇒ 1μF	±5% ⇒ ±20%	630 V ⇒ 3 500 V	in house	AC and pulse current.
olypro	1,88°C	PM 98 - PM 980 - PM 981	Metallized plastic film	25μF ➡ 1 600μF	\pm 10 % \pm 20 %	300 V ⇒ 1 200 V	in house	Filtering, energy storage, flash.
Metallized polypropylene	- 40°C	PP 78 A - PP 78 R - PP 78 S	Metallized polypropylene	1 nF 🖈 10.2 μF	±1% ⇒ ±20%	160 V ⇒ 630 V	UTEC/NFC	AC/DC current, standard applications.
etalliz	-55)-	PPS 13 - PPS 16 A - PPS 16 R PP 318 - PP 418	Polypropylene + foil	100 pF ⇒ 603 nF	±1% ⇒ ±20%	63 V ➡ 1000 V	in house	AC/DC and pulse current.
Ž	ات ا	RA PS	Metallized polypropylene+foil	100 pF ➪ 22 μF	±1% ⇒ ±20%	630 V ⇒ 2 000 V	in house	AC and pulse current.
	-40°C	682P		5.0μF ⇒ 100μF	$+20\% -10\%$, $\pm 10\%$	800 ➡ 1 200 V		Energy storage.
	7+ 0	684P		5.0µF ⇒ 175µF	$+20\% -10\%$, $\pm 10\%$	400 ➡ 1 000 V		
	-55 +70	730G		0.01µF ➡ 2.5µF	±20% ⇒ ±5%	850 ⇒ 3 000 V		AC / & Snubber.
	-55 +85	781P		18.0µF 🕏 400.0µF	±20% ⇒ ±10%	600 ➡ 1 800 V		
[P.P]		700P		0.01μF ⇒ 1.0μF	±20% ⇒ ±5%	200 ⇒ 800 V		
Polypropylene (P.P)		709G	Polypropylene	1 nF 🖈 4.7 μF	±20% ⇒ ±5%	160 ➡ 2 000 V		AC / DC & Pulse current.
propy		710P	(P.P)	1 nF 🖈 1.0 μF	±20% ⇒ ±5%	200 ⇒ 800 V	MIL QPL	
Poly	+105°	730P/731P		22 nF 🖈 10.0 μF	±20% ⇒ ±5%	160 ➡ 630 V		AC / DC & Pulse current.
	-55°C	734G		0.47µF 🖈 10.0µF	±20% ⇒ ±5%	400 ⇔ 600 V		Low inductance.
		735P		1.0µF 🕏 30.0µF	±20% ⇒ ±5%	100 ⇒ 400 V	MIL QPL	SMPS
		744G		0.47µF ⇒ 3.5µF	±20% ⇒ ±5%	600 V		
		752P		0.10µF ⇒ 2.5µF	±20% ⇒ ±5%	800 ⇔ 3 000 V		IGBT Snubber.
	ں	118P		1 nF 🖈 12.0 μF	$\pm 20\%$ to $\pm 5\%$	200 ⇒ 1 000 V	MIL QPL	Bypass, coupling
	55°C +125°I	103P		1 nF 🖈 1.0 μF	$\pm20\%$ to $\pm10\%$	200 ⇒ 600 V	MIL QPL	RFI
_	- 55°C	911P		0.10μF ⇒ 2.7μF	10%	400 V		
Paper / Foil		CL53/54/55	Paper / Foil	0.05μF ⇒ 10μF	$+20\% -10\%. \pm 10\%$	100 ⇒ 1 000 V	MIL QPL	Bypass, coupling, filtering High temperature +200°C
Рареі	65°C 25°C	131P	тарет / топ	1 nF 🖈 1.0 μF	$\pm 20\%$ to $\pm 5\%$	200 ⇒ 1 000 V	MIL QPL	
	9- 117	CQ72		0.10µF ⇒ 15.0µF	±20% ⇒ ±10%	400 ➡ 12 500 V	MIL QPL	High Voltage
	-40℃	282P		10.0μF ⇒ 200μF	+20% -10%. ±10%	2 000 🕏 4 000 V		Energy storage
	+ 0	681P		5.0μF ⇒ 100μF	+20% -10%. ± 10%	1 000 🖈 2 500 V		Energy storage
w	100]	PPA - PPA FR - PPA M		1.5 μF ⇒ 260 μF	±5% ⇒ ±20%	260 V _{AC} ⇒ 900 V _{AC}	in house	Motor run, fluorescence, compensation.
ronic	2°C (+	PP 44 R/A - PP 411 PP 44 RS - 44 A2	Metallized polypropylene	0.1 μF ⇒ 400 μF	±5% ⇒ ±20%	300 V ⇔ 2400 V	in house	IGBT capacitors, protection / turn off thyristors GTO, medium frequency
elect	ງ.28+ງ.ເ	PP 88 - IGB 99		47 nF ⇒ 7.5 μF	±5% ⇒ ±20%	800 V ⇒ 4000 V 1.5kV _{GTO} ⇒ 5.6kV _{GTO}	in house	tuning.
Power electronics) –40	PLP PAM	Impregnated P.P +paper	22 nF 🖈 300 μF	±5% ⇒ ±20%	160 V ⇒ 10000 V	in house	Commutation, rapid discharges, energy storage, filtering, protection.
	[-55	BI 73 A - BI 73 R R 73 A - R 73 R	Bi-film Polyester + foil	1 nF 🖈 2.2 μF	±5% ⇒ ±20%	$1000V_{DC}$ ⇒ $2200V_{DC}$ Ucrete ⇒ $5000V$	in house	Filtering, protection.
	+125°C	CA 1 - CA 2 CA 17 to CA 19		4.7 pF ⇒ 100 nF	$\pm 0.5 \text{pF}$ or $\pm 1 \% \Rightarrow \pm 10 \%$	500 V ➡ 5000 V		Filtering circuits, delay line circuits, oscillators, pulse circuits,
Mica	55°C +12	CA 15 - 20 - 30 - 40 CA 152 to 158	Silvered mica	4.7 pF ⇒ 15 nF	±1pF or ±1 % ⇒ ±10%	63 V ⇒ 500 V	CECC Acc. MIL C 5	H.F. generators, emmission lines, D.C. blocking circuits, coupling,
	-55	CM 04 to CM12 CMR 03 to CMR 07		1 pF 🖈 91 nF	$\pm 0.5 \text{pF}$ or $\pm 1 \% \Rightarrow \pm 5 \%$	50 V ⇔ 500 V		measurement



ELECTROLYTIC ALUMINUM CAPACITORS

Due to their technology electrolytic aluminum capacitors are polarised and can deliver the highest capacitance values of all capacitors families (up to 2.2 Farads).

Because EXXELIA ${
m SIC\,SAFC0}$ manufacture their own electrolytes, our capacitors show the largest lifetime of the market.

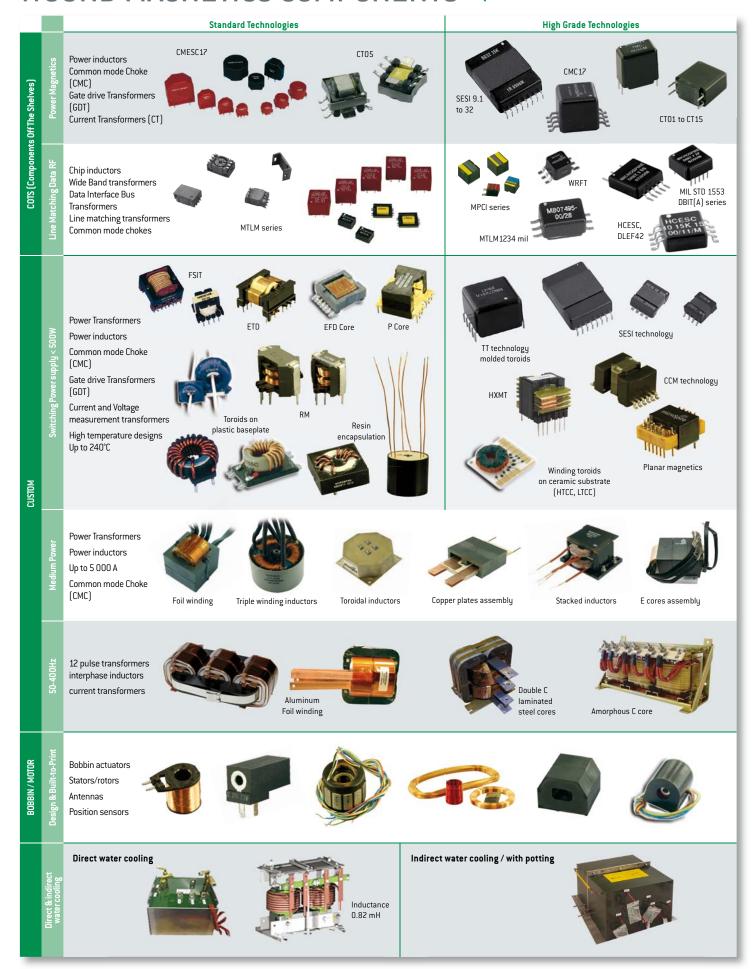
Therefore they are used in D.C. voltage applications for storing energy (lightning flash-lamps, welding machines, radiology, radars...) and time delay devices.



	(°C)	Product range	Sizes 0 x h (mm)	Capacitance	Voltage	Main characteristics
	-55 +125	FELSIC 125FRS	36x52 to 90x145	220 to 150 000 μF	16 to 350 V	Low ESR, +125°C
	ر	FELSIC 105TFRS	36x47 to 77x144	470 to 68 000 μF	10 to 100 V	Very low ESR
	–55°C to +105°C	FELSIC HV	51x81 to 90x200	1 000 to 47 000 μF	160 to 450 V	Extreme Long life, High ripple
nals	55°C to	FELSIC 105	36x52 to 90x200	100 to 470 000 μF	16 to 450 V	Extreme Long life
Screw terminals	'	FELSIC 105 LP	90x67	1 500 to 220 000 µF	10 to 450 V	105 with Low Profile can
Scre		FELSIC CAPAX	36x44 to 90x200	100 μF to 2.2 F	10 to 500 V	High energy density
) +85°C	FELSIC 85	36x52 to 90x200	68 to 680 000 µF	10 to 630 V	Standard 85°C
	–55°C to +85°C	FELSIC 85M	36x52 to 90x200	68 to 680 000 µF	10 to 630 V	Standard 85°C $\pm 20\%$ tolerance
		FELSIC 039- FELSIC 037	36x47 to 77x144	100 to 150 000μF	10 to 400 V	Standard C039 type (railway maintenance standard)
	-55°C to 145°C	ALSIC 145	10x16 to 16x25	22 to 4 700 μF	10 to 100 V	High temperature range, Long life
	–55°	ALSIC 145 20g	18x20 to 22.5x25	470 to 2 200 μF	10 to 115 V	High temp. range, Long life, withstand 20g vibrations
type		CUBISIC	35x35x16. 35x50x16	100 to 33 000 μF	10 to 450 V	Non cylindrical case, Withstand 20g vibrations, High energy density
Radial leaded type	ວ.20	CUBISIC LP	45x35x12 to 45x75x12	220 to 68 000 μF	10 to 400 V	Non cylindrical case, Withstand 20g vibrations, High energy density
Radial	–55°C to +105°C	ALSIC IR	10x16 to 16 x25	15 to 5 600 μF	10 to 100 V	Standard radial type
	-55°	ALSIC HV	10x16 to 35.5x40	10 to 2 200 μF	160 to 500 V	Standard radial type
		ALSIC 20g	18x20 to 35.5x25	33 to 80 000 µF	10 to 500 V	Withstand 20g vibrations
	–55 +125	Snapsic 125	22x25 to 35x50	470 to 47 000 μF	16 to 100 V	High temperature range, Long Life
		Snapsic HV	22x25 to 35x50	47 to 2 200 μF	160 to 500 V	Long Life, High ripple current
		Snapsic 105	22x25 to 35x50	22 to 68 000 μF	16 to 500 V	Standard 105°C type
Snap in type	-55°C to 105°C	Snapsic 105 4P	35x50 to 45x75	330 to 150 000 µF	16 to 550 V	Standard 105°C type with 4Pins
Snap i		Snapsic 105 LP	45x21 to 45x40	150 to 68 000 μF	16 to 500 V	Low Profile 105°C with 4 Pins
	85°C	Snapsic Capax	22x25 to 35x50	33 to 47 000 μF	25 to 500 V	High energy density
	–55°C to 8	Snapsic	22x25 to 35x50	22 to 47 000 μF	16 to 500 V	Standard 85°C type
	-56	Snapsic 4P	35x50 to 45x100	330 to 150 000 µF	16 to 500 V	Standard 85°C type with 4 Pins
	–55°C to +150°C	Prorelsic 145	14x30 to 25x75	6.8 to 10 000μF	16 to 450 V	High temperature Long life
ø	-55 +15	Vacsic 150	14x30 to 16x30	6.8 to 3 300 µF	16 to 450 V	High temperature Long life, Withstand 45g vibrations
Axial type	-55 +125	Prorelsic 125	12x25 to 25x75	1 to 15 000 μF	10 to 350 V	125°C Long life
4	5 to 5°C	Sical /Sical CO42	6.5x19 to 25x75	6.8 to 47 000 μF	10 to 630 V	Standard 105°C type
	−55 to +105°C	Vacsic 105	12x25 to 16x30	15 to 4 700 μF	10 to 450 V	Standard 105°C type; Withstand 45g vibrations.



WOUND MAGNETICS COMPONENTS



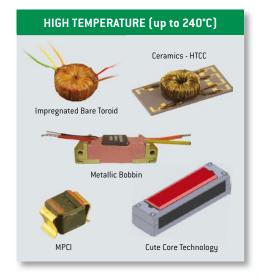


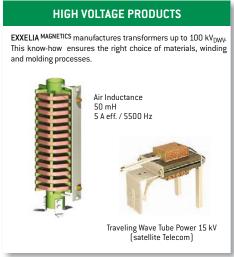
EXXELIA MAGNETICS, EXXELIA RAFTABTRONICS and EXXELIA DEYOUNG specialize in the design, manufacture and sale of magnetic components, including wound magnetics, inductors, transformers, motors, sensors and actuators for high performance applications.

Our technology offer includes standard linear and toroidal technologies, as well as Chameleon Concept Magnetics technology (CCM), Toroidal Transfer

Molded Technology (TT), SESI planar/low profile technology, and Aluminum Foil Winding technology (AFW) all optimized to meet the most demanding applications.

EXXELIA GROUP offers a complete range of products, providing solutions for highly demanding requirements such as High Voltage, High Temperature, and Power Levels up to 300 kVA.

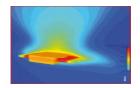


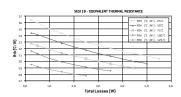


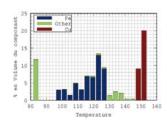


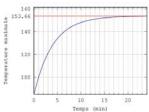
THERMAL MANAGEMENT

EXXELIA GROUP invests in R&D and makes extensive studies on the thermal management of magnetics, including loss calculations, design rules, thermal resistance and thermal modeling. We have available, a complete database of thermal resistances for all standard magnetics packages and have developed specific software for designing optimized compact components.









CATALOG PRODUCTS

	Series	Current	Inductance	Temperature Range	Frequency	Notes
<u> </u>	MPCI 10000, 12000, 20000	15 mA 🖈 1 000 mA	0.010µН ➪ 1 000µН	-55°C ⇒ +125°C	7.9 MHz ➡ 500 MHz	QPL, Space Qualified
Chip	MPCI H01	100 mA 🖈 1 500 mA	0.38µН ➪ 100µН	-55°C ⇒ +125°C		QPL, Space Qualified
=	MPCI 233 H01	100 mA 🖈 1 500 mA	0.38µН ➪ 100µН	up to +175°C		High Temperature
C.Mode Choke	CMC 15, CMC 18, CMC 22	0.55 A ⇒ 14.3 A	60 µН ➪ 4 900 µН	–55°C ⇒ +125°C		QPL, Space Qualified
ڲٙڋ	CMC 14, CMC 17	1.1 A ➡ 11.7 A	140µН ➪ 69 200µН	–55°C ⇒ +125°C		
<u></u>	SESI 9.1	0.045 A ➡ 6 A	1µН ➪ 6 800µН	-55°C ⇒ +125°C	max 1 MHz	QPL, Space Qualified
nductor	SESI 14, 15	0.28 A ⇔ 14 A	1.5µH ➡ 2 290µH	-55°C ⇒ +125°C	max 1 MHz	QPL, Space Qualified
	SESI 18, 22, 32	0.8 A ⇒ 24 A	4.9μH ⇒ 4 709μH	-55°C ⇒ +125°C	max 1 MHz	QPL, Space Qualified
	Series	ET	Turn Ratio	Temperature Range	Frequency (duty cycle 50%)	Notes
Gate drive transfo.	GTD 15	60/80 Vμs	1:1.52/1:1:1	-55°C ⇒ +125°C	up to 500 kHz	Aeronautic, Space
Gate	GTD 91	50/135 V.µs	1:1/1:1:1	-55°C ⇒ +125°C	up to 500 kHz	Aeronautic, Space
	Series	Current	Turn Ratio	Temperature Range	Frequency (Triangle Waveform)	Notes
Current transfo.	CT 15	17 A pk max.	1:50/1:200	-55°C ⇒ +125°C	6 kHz ➪ 100 kHz	Aeronautic, Space
fa C	CT 91	10 A pk max.	1:50/1:200	–55°C ⇒ +125°C	6 kHz ➪ 500 kHz	Aeronautic, Space
	DBIT / SBIT	MIL-STD-1553 Data	Bus Transformer	–55°C ⇒ +125°C	75 kHz ⇒ 1 MHz	Aerospace, ESA / EPPL

POSITION SENSORS & SLIP RINGS

EXXELIA TECHNOLOGIES designs and manufactures contact and contactless Position Sensors, Slip Rings and Hybrid Systems.





PRECISION MECHANIC

EXXELIA GROUP's Precision Mechanics division specialises in machining complex parts, from prototypes to medium series. Our best-in-class palletized-5-axis turning and milling equipment enable us to work with all types of material including titanium, inconel, 35NCD4 etc...

Assembly, high precision manual deburring and hydraulic tests can be carried out in our workshop.









EMI-RFI FILTERS



EXXELIA TECHNOLOGIES range of EMI-RFI filters are mainly low-pass filters designed to remove efficiently high-frequency interferences and parasites.

Nowadays filters function are required for:

- Data signal integrity,
- Power supply performance,
- EMC standard compliance.



	T°	Model	Current	Voltage	Performance	Qualification	Use
	(ث	Feedthrough 0 3 - 0 4 - 0 6 - 0 10 (mm)	Up to 15 A	Up to $500\mathrm{V}_\mathrm{DC}$ and $115\mathrm{V}_\mathrm{AC}400\mathrm{Hz}$	Up to 80dB from 10 kHz to 10 GHz	Qual. ESA, Air, Compliant MIL 461, DO 160	Space, Aeronautic, Defense, Industry.
Filters	to 175	Feedthrough 0 17 (mm)	Up to 30 A	Up to 3 000 V_{DC} and 200 V_{AC} 400 Hz	Up to 80dB from 10 kHz to 10 GHz	Air qualified, Compliant MIL 461, D0160	Aeronautic, Defense, Industry.
EMI-RFI Fil	:5°C (up	Multi ways Filters	Up to 15 A	Up to 500 V_{DC} and 115 V_{AC} 400 Hz	Up to 80dB from 10 kHz to 10 GHz	in house	Aeronautic, Defense, Industry.
EM	5°C +12	Surface mount FCMS - CFCMS	10 A (20 A for HI version)	Up to 500 V_{DC} and 115 V_{AC} 400 Hz	Up to 70 dB from 10 kHz to 10 GHz	ESA EPPL	Space, Aeronautic, Defense, Industry.
		SPF	0.1 A ➡ 500 A	25 V ➡ 3 000 V eff.	1 kHz ➡ 10 GHz	in house	Custom design

ENERGY FILTERS

Following 50 years heritage in Defense market, EXXELIA TECHNOLOGIES offers highly performant, robust and reliable solutions to protect from different EMC phenomenon all kind of signal such as:

- Power supply,
- Control lines,
- Data communication...





	T°	Model	Current	Voltage	Performance	Use		
Filters		Feedthrough Tube filters	Up to 500 A	Up to 1 000 $\rm V_{DC}$ and 400 $\rm V_{AC}$	Up to 100 dB Up to 18 GHz	Single lines power supply.		
	-85°C	Power cabinets	Up to 2 500 A	Up to 440 V _{AC} (50-800Hz)	Up to 100 dB from 10 kHz to 18 GHz	Three or single phase power supply for TEMPEST and HEMP		
EMC	_55°C	Data communication	Up to 1A	-	Up to 100 dB Up to 18 GHz	Up to 100MHz bandwidth data signal for TEMPEST and HEMP		
		Custom filters		Additional prote	Additional protection for energy and signal filtering.			

COMPONENTS & SUB-ASSEMBLIES MANUFACTURING



With two production units, separated by less than 10 km and located both in Casablanca (Morocco), **EXXELIA** MAROC offers to its customers a subcontracting capability on its two main competences fields with high technology processes as: wire bonding, vacuum metallization, RF test equipments, reliability test equipment.

Complex electronic modules or components assembly:

- RF diodes packaging,
- RF circulators assembly,
- quartz hybrid oscillators assembly,
- high frequency filters assembly,
- opto electronic components,
- antennas, sensor.

Built-to-print for overmoulding, wiring and harnessing, rotors, stators, actuators.

EXXELIA VIETNAM is locate in Ho Chi Minh City and dedicated to Medium to High volume markets requesting traceability for processes and raw materials.

(**■**) GROUP



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Power & Microwave Technologies Global Sales Support

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Richardson Electronics has been an industry-leader in providing high-quality products and outstanding engineering support for nearly 70 years. Our extensive global distribution network and world-class partners provide our customers with innovative technologies, products and services.

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